BFR94A

NPN 5 GHz wideband transistor

Rev. 4 — 2 October 2014

Product data sheet

1. Product profile

1.1 General description

NPN wideband transistor in a plastic SOT23 package. PNP complement; BFT92

1.2 Features and benefits

- High power gain
- Low noise figure
- Low intermodulation distortion
- AEC-Q101 qualified

1.3 Applications

RF wideband amplifiers and oscillators

1.4 Quick reference data

Table 1. Quick reference data

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{CBO}	collector-base voltage		-	-	20	V
V _{CEO}	collector-emitter voltage		-	-	15	V
I _C	collector current		-	-	25	mA
P _{tot}	total power dissipation	$T_{sp} \le 95 \ ^{\circ}C$	-	-	300	mW
C _{re}	feedback capacitance	$I_{C} = i_{C} = 0 \text{ mA}; V_{CE} = 10 \text{ V};$ f = 1 MHz	-	0.35	-	pF
f _T	transition frequency	I _C = 15 mA; V _{CE} = 10 V; f = 500 MHz	-	5	-	GHz
G _{UM}	unilateral power gain	I_{C} = 15 mA; V_{CE} = 10 V; T_{amb} = 25 °C				
		f = 1 GHz	-	14	-	dB
		f = 2 GHz	-	8	-	dB
NF	noise figure	$\begin{split} I_{C} = 5 \text{ mA; } V_{CE} = 10 \text{ V; } f = 1 \text{ GHz;} \\ \Gamma_{S} = \Gamma_{opt}; T_{amb} = 25 \text{ °C} \end{split}$	-	2.1	-	dB
Vo	output voltage	$\begin{split} \text{IMD} &= -60 \text{ dB; } \text{I}_{\text{C}} = 14 \text{ mA;} \\ \text{V}_{\text{CE}} &= 10 \text{ V; } \text{R}_{\text{L}} = 75 \ \Omega; \\ \text{f}_{\text{p}} + \text{f}_{\text{q}} - \text{f}_{\text{r}} = 793.25 \text{ MHz} \end{split}$	-	150	-	mV



2. Pinning information

2 1 2 sym021

3. Ordering information

Table 3. Ordering information					
Type number	Package				
	Name	Description	Version		
BFR94A	-	plastic surface-mounted package; 3 leads	SOT23		

4. Marking

Table 4. Marking		
Type number	Marking code	Description
BFR94A	NL*	* = p : made in Hong Kong
		* = w : made in China

5. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

	Parameter	Conditions	Min	Max	Unit
V _{CBO}	collector-base voltage	open emitter	-	20	V
V _{CEO}	collector-emitter voltage	open base	-	15	V
V _{EBO}	emitter-base voltage	open collector	-	2	V
I _C	collector current		-	25	mA
P _{tot}	total power dissipation	$T_{sp} \le 95 \text{ °C}; \text{ see } Figure 2$	-	300	mW
T _{stg}	storage temperature		-65	+150	°C
Tj	junction temperature		-	+150	°C

[1] T_{sp} is the temperature at the solder point of the collector pin.

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6. Thermal characteristics

Table 6.	Thermal characteristics				
Symbol	Parameter	Conditions		Тур	Unit
R _{th(j-sp)}	thermal resistance from junction to solder point	T _{sp} ≤ 95 °C	<u>[1]</u>	260	K/W

[1] T_{sp} is the temperature at the solder point of the collector pin.

7. Characteristics

Table 7.	Characteristics					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _{CBO}	collector-base cut-off current	I _E = 0 A; V _{CB} = 10 V	-	-	50	nA
h _{FE}	DC current gain	$I_C = 15 \text{ mA}; V_{CE} = 10 \text{ V}; \text{ see } \frac{\text{Figure 3}}{100000000000000000000000000000000000$	65	90	135	
C _c	collector capacitance	$I_E = i_e = 0 \text{ A}; V_{CB} = 10 \text{ V}; f = 1 \text{ MHz}:$ see Figure 4	-	0.6	-	pF
C _e	emitter capacitance	$I_{C} = i_{c} = 0 \text{ A}; V_{EB} = 10 \text{ V}; f = 1 \text{ MHz}$	-	1.2	-	pF
C _{re}	feedback capacitance	$I_{C} = i_{c} = 0 \text{ mA}; V_{CE} = 10 \text{ V}; f = 1 \text{ MHz}$	-	0.35	-	pF
f _T	transition frequency	$I_C = 15 \text{ mA}; V_{CE} = 10 \text{ V}; f = 500 \text{ MHz};$ see <u>Figure 5</u>	-	5	-	GHz
G _{UM}	unilateral power gain	$I_{C} = 15 \text{ mA}; V_{CE} = 10 \text{ V}; T_{amb} = 25 \text{ °C}$ [1]				
		f = 1 GHz	-	14	-	dB
		f = 2 GHz	-	8	-	dB
NF	noise figure	I _C = 5 mA; V _{CE} = 10 V; $\Gamma_S = \Gamma_{opt}$; T _{amb} = 25 °C; see Figure 12 and Figure 13				
		f = 1 GHz	-	2.1	-	dB
		f = 2 GHz	-	3	-	dB
Vo	output voltage	[2][3]	-	150	-	mV
IMD2	second-order intermodulation distortion	see <u>Figure 15</u> [2][4]	-	-50	-	dB

[1] G_{UM} is the maximum unilateral power gain, assuming S_{12} is zero and

$$G_{UM} = 10 \log \frac{|S_{2I}|^2}{(I - |S_{II}|^2)(I - |S_{22}|^2)} \ dB.$$

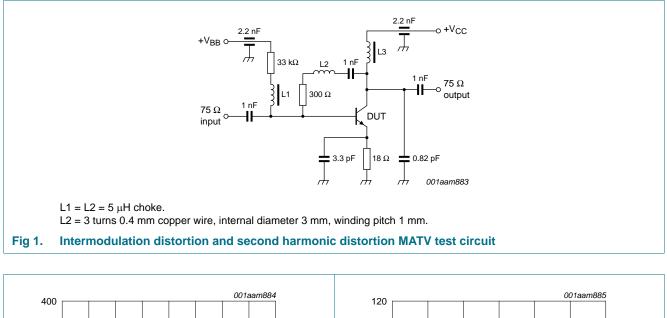
[2] Measured on the same crystal in a SOT37 package (BFR90A).

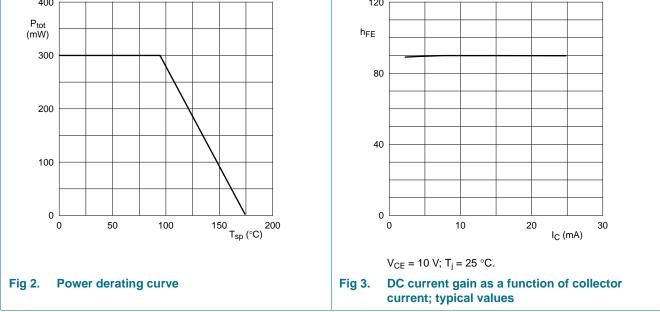
[3] IMD = -60 dB (DIN 45004B); I_C = 14 mA; V_{CE} = 10 V; R_L = 75 Ω; VSWR < 2; T_{amb} = 25 °C; V_p = V_O at IMD = -60 dB; f_p = 795.25 MHz; V_q = V_O -6 dB at f_q = 803.25 MHz; V_r = V_O -6 dB at f_r = 805.25 MHz; measured at f_p + f_q - f_r = 793.25 MHz
[4] I_C = 14 mA; V_{CE} = 10 V; R_L = 75 Ω; VSWR < 2; T_{amb} = 25 °C; V_p = 60 mV at f_p = 250 MHz;

 $V_q = 60 \text{ mV}$ at $f_p = 560 \text{ MHz}$; measured at $f_p + f_q = 810 \text{ MHz}$

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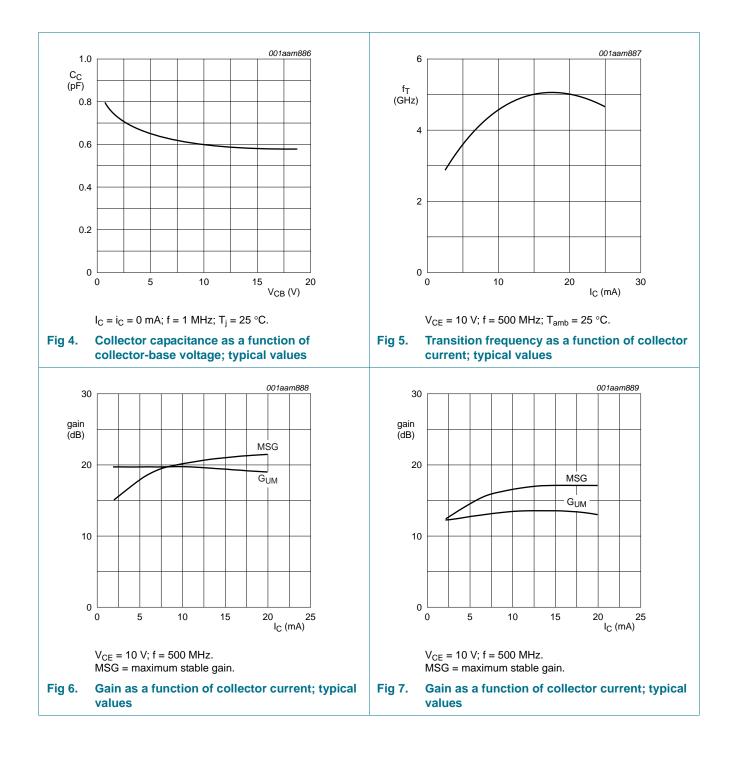
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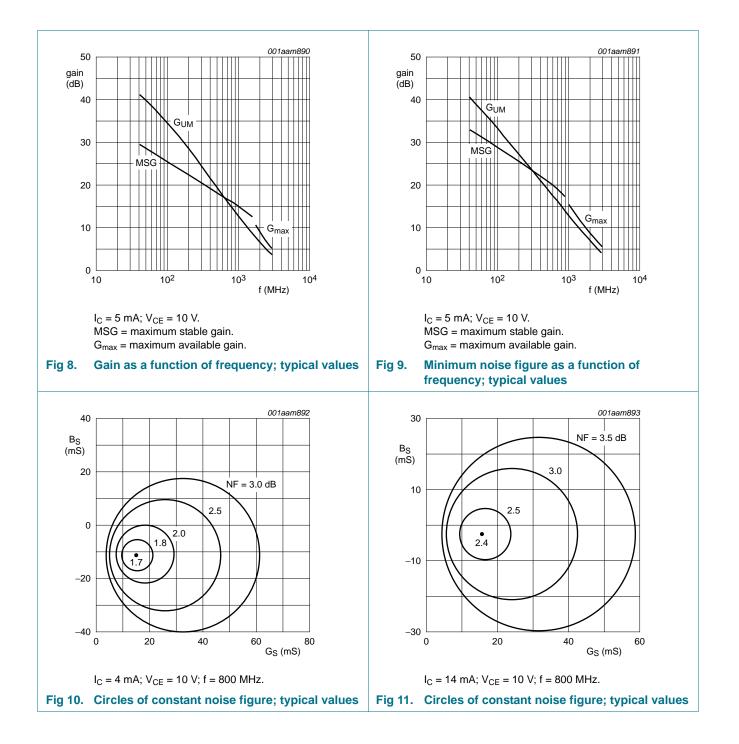


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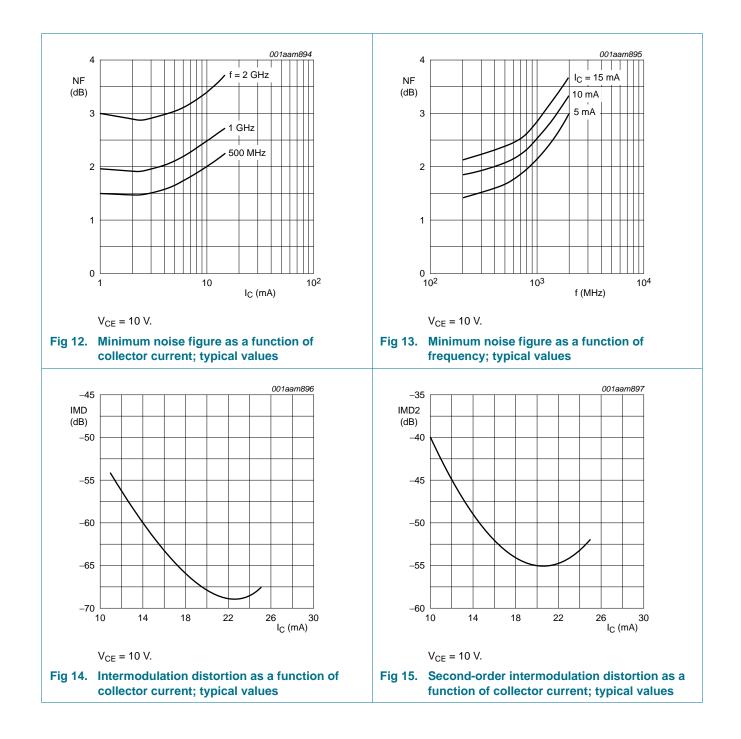
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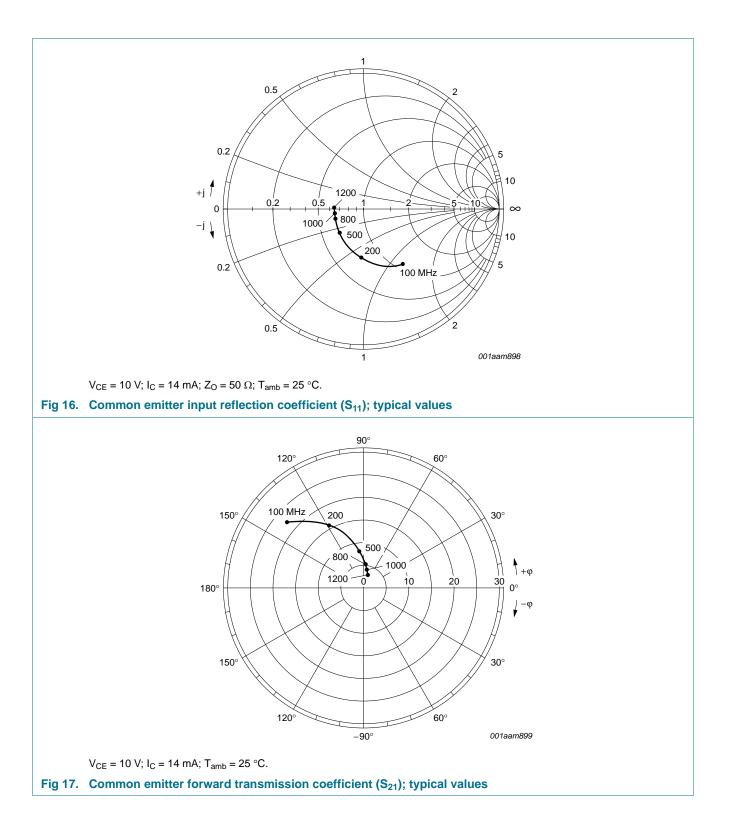


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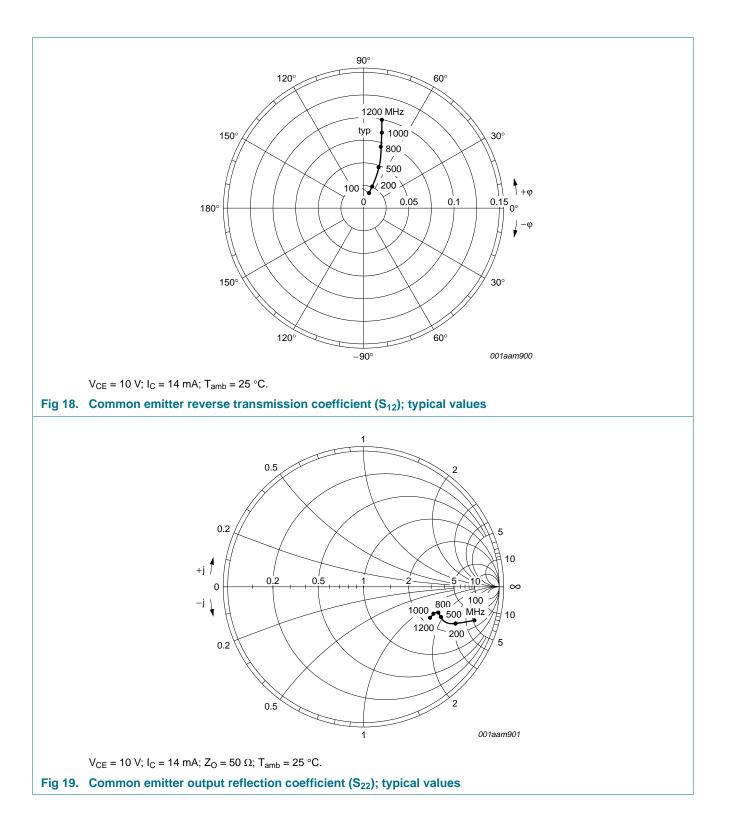
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8. Package outline

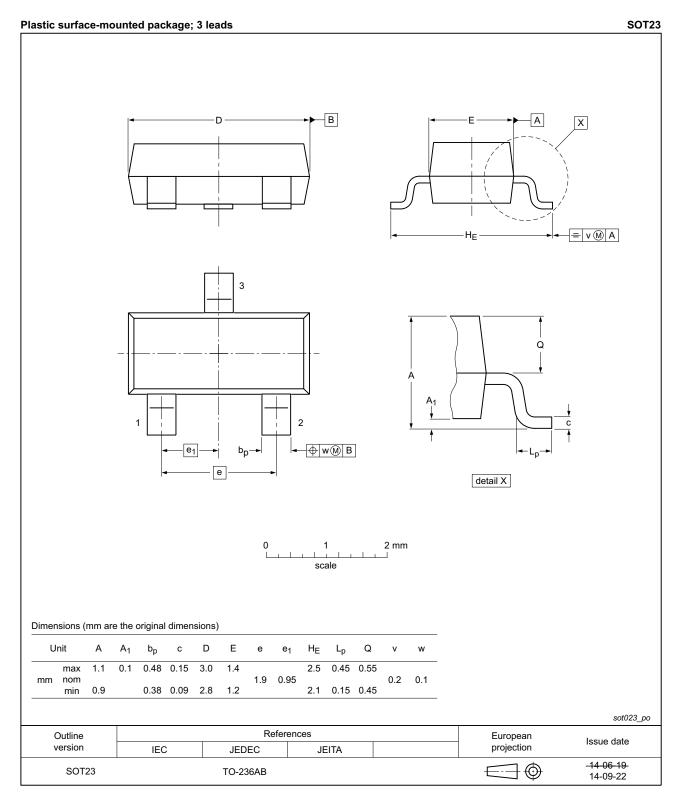


Fig 20. Package outline SOT23

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9. Abbreviations

Table 8. Abbreviations				
Acronym	Description			
NPN	Negative Positive Negative			
PNP	Positive Negative Positive			
RF	Radio Frequency			
MATV	Master Antenna Television			
VSWR	Voltage Standing Wave Ratio			

10. Revision history

Table 9.Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
BFR94A v.4	20141002	Product data sheet	-	BFR94A v.3
Modifications:	• Table 2 on page	ge 2: changed graphic symbol		<u>.</u>
	• Figure 20 on p	bage 10: updated		
BFR94A v.3	20101115	Product data sheet	-	BFR94A v.2
BFR94A v.2	19971204	Product data sheet	-	-

11. Legal information

11.1 Data sheet status

Document status[1][2]	Product status ^[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

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